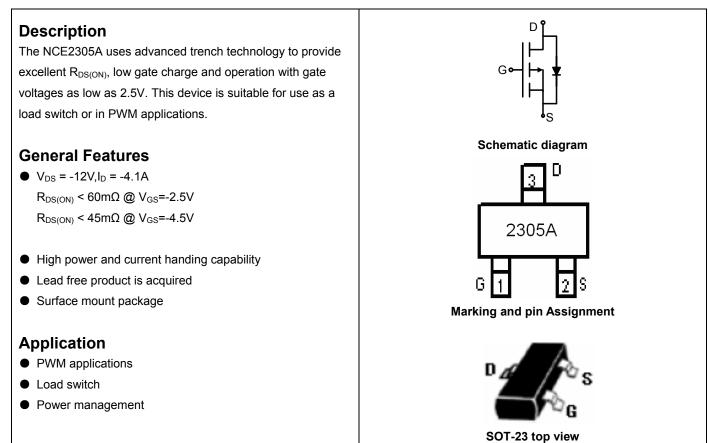


# NCE P-Channel Enhancement Mode Power MOSFET



#### Package Marking And Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
2305A	NCE2305A	SOT-23	Ø180mm	8 mm	3000 units

#### Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	-12	V
Gate-Source Voltage	Vgs	±12	V
Drain Current -Continuous	Ι <sub>D</sub>	-4.1	A
Drain Current -Pulsed (Note 1)	I <sub>DM</sub>	-15	А
Maximum Power Dissipation	PD	1.7	W
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 150	°C

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	R <sub>θJA</sub>	74	°C <b>/W</b>
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#### Electrical Characteristics (T<sub>A</sub>=25<sup>°</sup>Cunless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						



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Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =-250µA	-12	-18	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-12V,V <sub>GS</sub> =0V	-	-	-1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±12V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =-250µA		-0.7	-1.0	V
Drain Course On State Desistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-4.1A	-	30	45	mΩ
Drain-Source On-State Resistance		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-3A	-	43	60	
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =-5V,I <sub>D</sub> =-2A	5	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	- V <sub>DS</sub> =-4V,V <sub>GS</sub> =0V,	-	740	-	PF
Output Capacitance	C <sub>oss</sub>	– V <sub>DS</sub> –-4V,V <sub>GS</sub> –0V, – F=1.0MHz	-	290	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	- F - 1.0101112	-	190	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	12	-	nS
Turn-on Rise Time	tr	$V_{DD}$ =-4V,I <sub>D</sub> =-3.3A,	-	35	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$R_{L}$ =-1.2 $\Omega$ , $V_{GEN}$ =-4.5 $V$ , $R_{g}$ =1 $\Omega$	-	30	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	10	-	nS
Total Gate Charge	Qg		-	7.8	-	nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =-4V,I <sub>D</sub> =-4.1A,V <sub>GS</sub> =-4.5V	-	1.2	-	nC
Gate-Drain Charge	Q <sub>gd</sub>		-	1.6	-	nC
Drain-Source Diode Characteristics	·		-		-	•
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =-1.6A	-	-	-1.2	V
Diode Forward Current (Note 2)	I <sub>S</sub>		-	-	4.1	Α

### Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

**2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.

**3.** Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.

4. Guaranteed by design, not subject to production



**NCE2305A** 



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## **Typical Electrical and Thermal Characteristics**

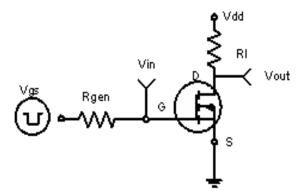
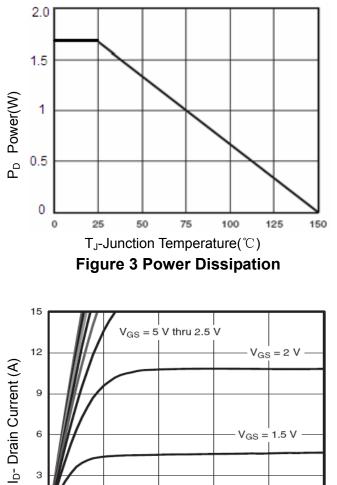
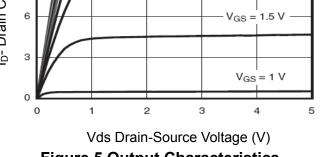
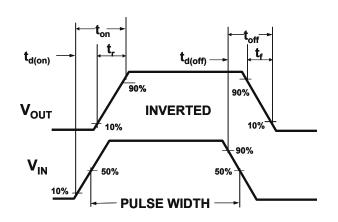


Figure 1:Switching Test Circuit





**Figure 5 Output Characteristics** 





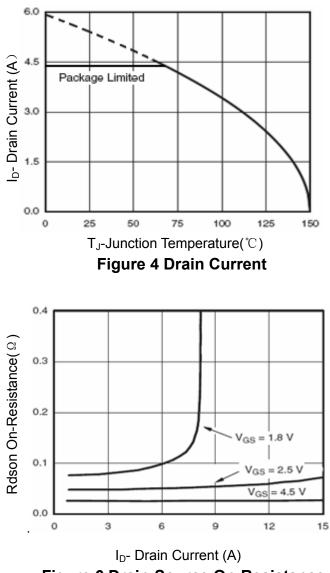


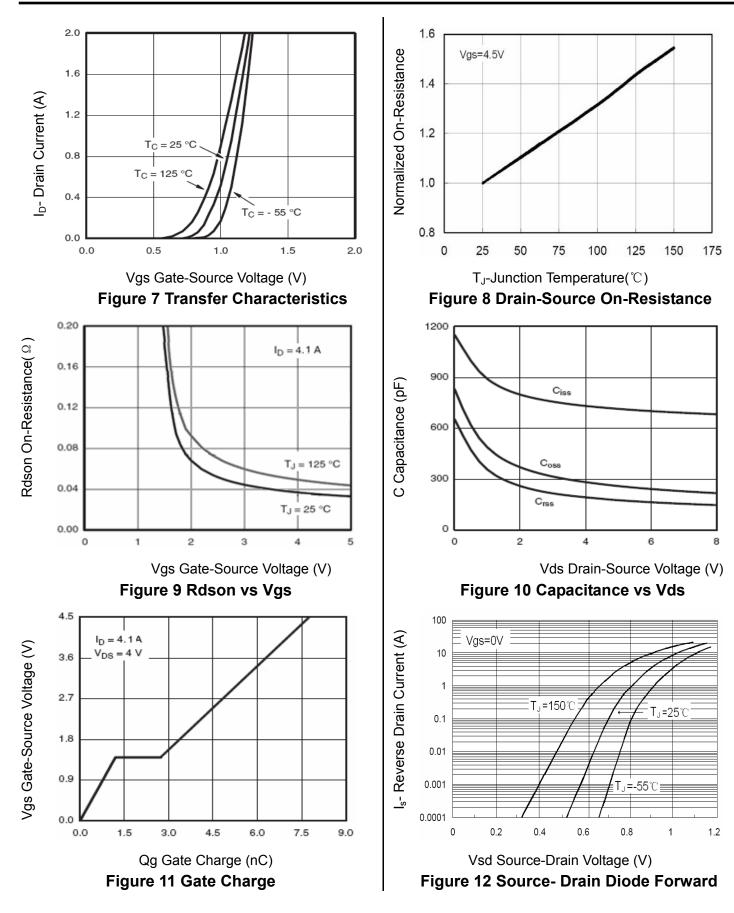
Figure 6 Drain-Source On-Resistance



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Pb Free Product

NCE2305A





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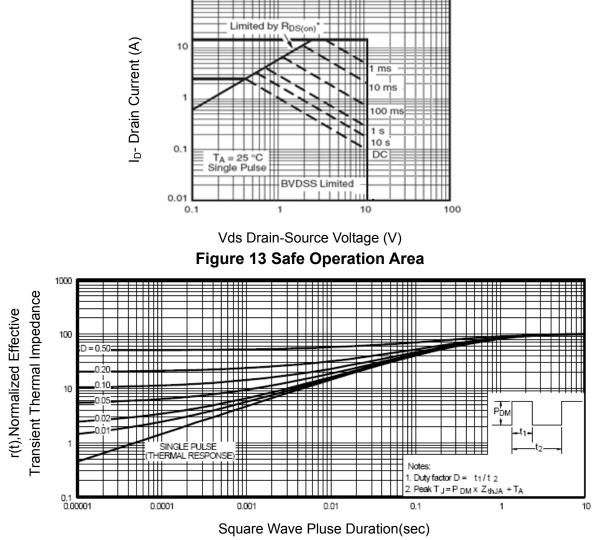


Figure 14 Normalized Maximum Transient Thermal Impedance

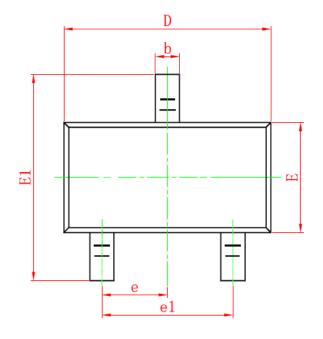


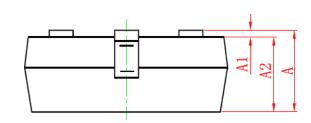
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## **SOT-23 Package Information**





	<u>0. 25</u>
	<u> </u>

Symbol	Dimensions in Millimeters			
	MIN.	MAX.		
Α	0.900	1.150		
A1	0.000	0.100		
A2	0.900	1.050		
b	0.300	0.500		
С	0.080	0.150		
D	2.800	3.000		
Е	1.200	1.400		
E1	2.250	2.550		
е	0.950TYP			
e1	1.800	2.000		
L	0.550REF			
L1	0.300	0.500		
θ	<b>0°</b>	<b>8°</b>		

### Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance  $\pm 0.10$ mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.





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